

## Single Phase Rectifier Bridges

PSB 105

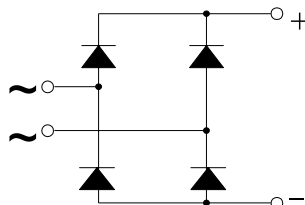
$$\frac{I_{dAVM}}{V_{RRM}}$$

**= 107A**

**= 800-1800 V**

## Preliminary Data Sheet

| $V_{RSM}$<br>$V$ | $V_{RRM}$<br>$V$ | Type       |
|------------------|------------------|------------|
| 800              | 800              | PSB 105/08 |
| 1200             | 1200             | PSB 105/12 |
| 1400             | 1400             | PSB 105/14 |
| 1600             | 1600             | PSB 105/16 |
| 1800             | 1800             | PSB 105/18 |



| Symbol                    | Test Conditions                    |            |               | Maximum Ratings |                  |
|---------------------------|------------------------------------|------------|---------------|-----------------|------------------|
| <b>I<sub>dAVM</sub></b>   | T <sub>C</sub> = 85°C, module      |            |               | 107             | A                |
| <b>I<sub>FSM</sub></b>    | T <sub>VJ</sub> = 45°C             | t = 10 ms  | (50 Hz), sine | 1500            | A                |
|                           | V <sub>R</sub> = 0                 | t = 8.3 ms | (60 Hz), sine | 1650            | A                |
|                           | T <sub>VJ</sub> = T <sub>VJM</sub> | t = 10 ms  | (50 Hz), sine | 1350            | A                |
|                           | V <sub>R</sub> = 0                 | t = 8.3 ms | (60 Hz), sine | 1500            | A                |
| <b>∫ i<sup>2</sup> dt</b> | T <sub>VJ</sub> = 45°C             | t = 10 ms  | (50 Hz), sine | 11250           | A <sup>2</sup> s |
|                           | V <sub>R</sub> = 0                 | t = 8.3 ms | (60 Hz), sine | 11300           | A <sup>2</sup> s |
|                           | T <sub>VJ</sub> = T <sub>VJM</sub> | t = 10 ms  | (50 Hz), sine | 9120            | A <sup>2</sup> s |
|                           | V <sub>R</sub> = 0                 | t = 8.3 ms | (60 Hz), sine | 9350            | A <sup>2</sup> s |
| <b>T<sub>VJ</sub></b>     |                                    |            |               | -40 ... + 150   | °C               |
| <b>T<sub>VJM</sub></b>    |                                    |            |               | 150             | °C               |
| <b>T<sub>stg</sub></b>    |                                    |            |               | -40 ... + 150   | °C               |
| <b>V<sub>ISOL</sub></b>   | 50/60 HZ, RMS                      | t = 1 min  |               | 2500            | V ~              |
|                           | I <sub>ISOL</sub> ≤ 1 mA           | t = 1 s    |               | 3000            | V ~              |
| <b>M<sub>d</sub></b>      | Mounting torque                    |            | (M5)          | 5               | Nm               |
|                           | Terminal connection torque         |            | (M5)          | 5               | Nm               |
| <b>Weight</b>             | typ.                               |            |               | 235             | g                |

## Features

- Package with screw terminals
- Isolation voltage 3000 V~
- Planar glasspassivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 148688

## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

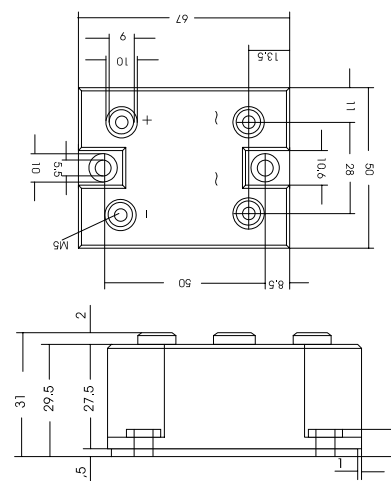
### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability

### Package, style and outline

Dimensions in mm (1mm = 0.0394")

| Symbol     | Test Conditions                               | Characteristic Value |
|------------|-----------------------------------------------|----------------------|
| $I_R$      | $V_R = V_{RRM}$ $T_{VJ} = 25^{\circ}\text{C}$ | $\leq 0.3$ mA        |
|            | $V_R = V_{RRM}$ $T_{VJ} = T_{VJM}$            | $\leq 8.0$ mA        |
| $V_F$      | $I_F = 150$ A $T_{VJ} = 25^{\circ}\text{C}$   | $\leq 1.6$ V         |
| $V_{TO}$   | For power-loss calculations only              | 0.8 V                |
| $r_T$      | $T_{VJ} = T_{VJM}$                            | 5 m $\Omega$         |
| $R_{thJC}$ | per diode; DC current                         | 0.83 K/W             |
|            | per module                                    | 0.21 K/W             |
| $R_{thJK}$ | per diode; DC current                         | 1.13 K/W             |
|            | per module                                    | 0.28 K/W             |
| $d_S$      | Creeping distance on surface                  | 17.6 mm              |
| $d_A$      | Creeping distance in air                      | 17.6 mm              |
| $a$        | Max. allowable acceleration                   | 50 m/s <sup>2</sup>  |



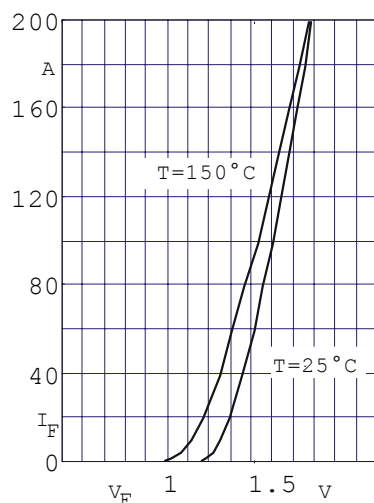


Fig. 1 Forward current versus voltage drop per diode

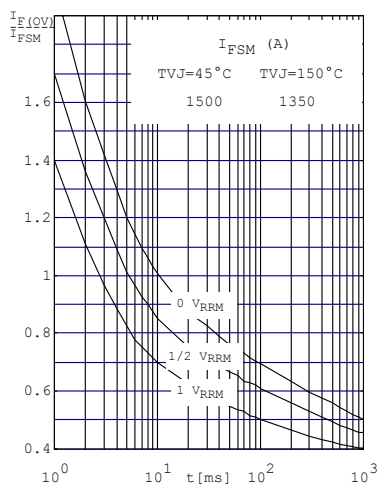


Fig. 2 Surge overload current per diode  $I_{FSM}$ : Crest value.  
t: duration

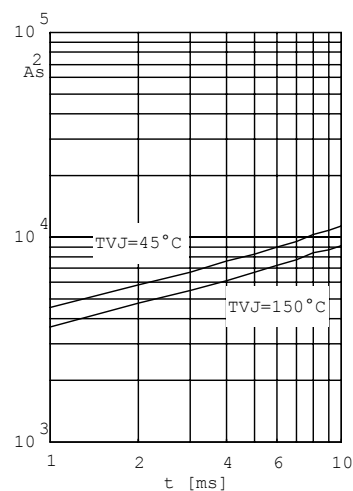


Fig. 3  $\int i^2 dt$  versus time (1-10ms) per diode (or thyristor)

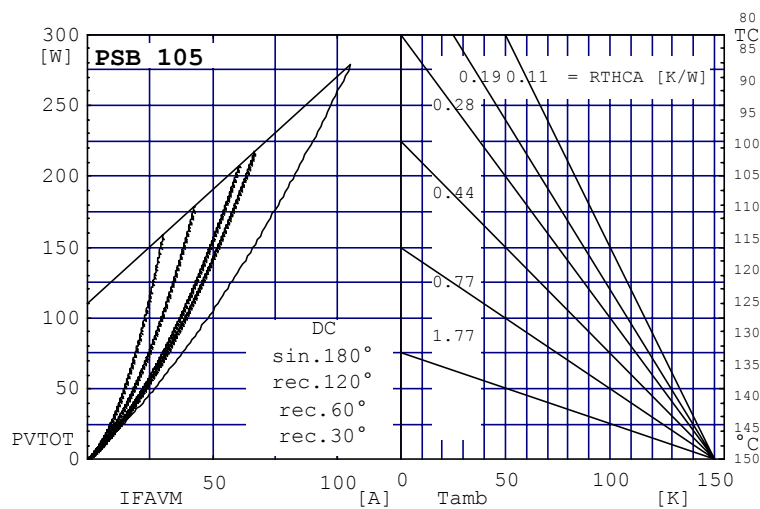


Fig. 4 Power dissipation versus direct output current and ambient temperature

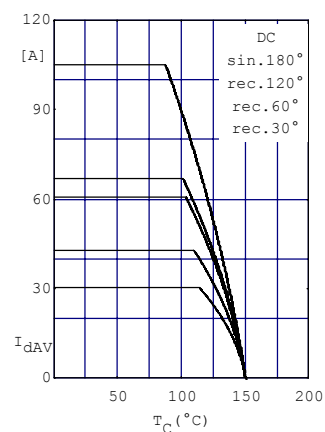


Fig. 5 Maximum forward current at case temperature

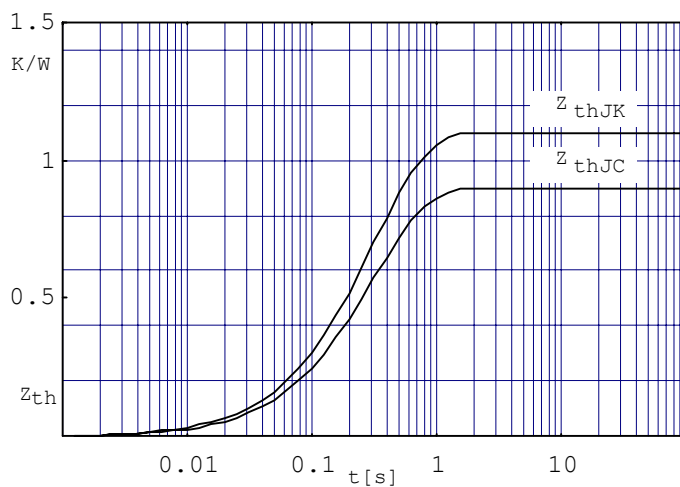


Fig. 6 Transient thermal impedance per diode (or thyristor), calculated